





#### **Features**

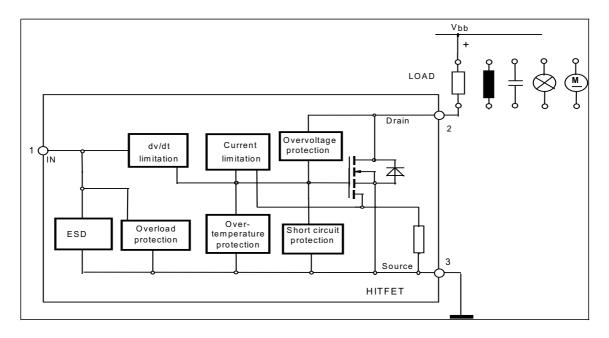
- Logic Level Input
- Input Protection (ESD)
- Thermal shutdown with latch
- Overload protection
- Short circuit protection
- Overvoltage protection
- Current limitation
- Status feedback with external input resistor
- Analog driving possible
- AEC qualified
- Green product (RoHS compliant)

#### **Application**

- All kinds of resistive, inductive and capacitive loads in switching or linear applications
- μC compatible power switch for 12 V and 24 V DC applications
- Replaces electromechanical relays and discrete circuits

## **General Description**

N channel vertical power FET in Smart SIPMOS<sup>®</sup> chip on chip technology. Providing embedded protection functions.



#### **Product Summary**

Drain source voltage	V <sub>DS</sub>	60	V
On-state resistance	R <sub>DS(on)</sub>	100	mΩ
Current limit	I <sub>D(lim)</sub>	7	Α
Nominal load current	I <sub>D(ISO)</sub>	3.5	Α
Clamping energy	E <sub>AS</sub>	1000	mJ





#### Maximum Ratings at Tj = 25 °C unless otherwise specified

Parameter	Symbol	Value	Unit
Drain source voltage	$V_{\mathrm{DS}}$	60	V
Drain source voltage for short circuit protection	V <sub>DS(SC)</sub>	32	
Continuous input current 1)	I <sub>IN</sub>		mA
$-0.2V \le V_{IN} \le 10V$		no limit	
$V_{IN}$ < -0.2V or $V_{IN}$ > 10V		<i>I</i> <sub>IN</sub>   ≤ 2	
Operating temperature	T <sub>j</sub>	- 40 +150	°C
Storage temperature	T <sub>stg</sub>	- 55 <b>+</b> 150	
Power dissipation	$P_{tot}$	50	W
$T_{\rm C}$ = 25 °C			
Unclamped single pulse inductive energy	E <sub>AS</sub>	1000	mJ
$I_{D(ISO)} = 3.5 A$			
Electrostatic discharge voltage (Human Body Model)	V <sub>ESD</sub>	3000	V
according to MIL STD 883D, method 3015.7 and			
EOS/ESD assn. standard S5.1 - 1993			
Load dump protection $V_{\text{LoadDump}^2} = V_{\text{A}} + V_{\text{S}}$	$V_{LD}$		
$V_{\rm IN}$ =low or high; $V_{\rm A}$ =13.5 V			
$t_d = 400 \text{ ms}, R_l = 2 \Omega, I_D = 0.5*3.5 A$		75	
$t_d = 400 \text{ ms}, R_l = 2 \Omega, I_D = 3.5 A$		70	

#### Thermal resistance

junction - case:	$R_{thJC}$	2.5	K/W
junction - ambient:	$R_{thJA}$	75	
SMD version, device on PCB: 3)	$R_{thJA}$	45	

<sup>&</sup>lt;sup>1</sup>In case of thermal shutdown a minimum sensor holding current of 500 µA has to be guaranteed (see also page 3).

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 $<sup>^{2}\</sup>textit{V}_{\text{Loaddump}}$  is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

 $<sup>^3</sup>$  Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with 6cm $^2$  (one layer, 70 $\mu$ m thick) copper area for Drain connection. PCB mounted vertical without blown air.



#### **Electrical Characteristics**

Parameter at T <sub>j</sub> =25°C, unless otherwise specified		Values			Unit
		min.	typ. max.		7
Characteristics				•	•
Drain source clamp voltage	V <sub>DS(AZ)</sub>	60	_	73	V
$T_{\rm j}$ = -40+ 150°C, $I_{\rm D}$ = 10 mA					
Off state drain current	I <sub>DSS</sub>	-	_	5	μΑ
$V_{\rm DS}$ = 32 V, $T_{\rm j}$ = -40+150 °C, $V_{\rm IN}$ = 0 V					
Input threshold voltage	V <sub>IN(th)</sub>	1.3	1.7	2.2	V
$I_{\rm D} = 0.7  {\rm mA}$	, ,				
Input current - normal operation, $I_D < I_{D(lim)}$ : $I_{IN(1)}$		-	30	60	μA
V <sub>IN</sub> = 10 V					
Input current - current limitation mode, $I_D = I_{D(lim)}$ :	I <sub>IN(2)</sub>	-	120	300	
V <sub>IN</sub> = 10 V					
Input current - after thermal shutdown, I <sub>D</sub> =0 A:	I <sub>IN(3)</sub>	800	2200	4000	
V <sub>IN</sub> = 10 V					
Input holding current after thermal shutdown 1)	I <sub>IN(H)</sub>				
<i>T</i> <sub>j</sub> = 25 °C		500	-	-	
<i>T</i> <sub>j</sub> = 150 °C		300	-	-	
On-state resistance					mΩ
$V_{\text{IN}}$ = 5 V, $I_{\text{D}}$ = 3.5 A, $T_{\text{j}}$ = 25 °C		-	90	120	
$V_{\text{IN}} = 5 \text{ V}, I_{\text{D}} = 3.5 \text{ A}, T_{\text{j}} = 150 ^{\circ}\text{C}$		-	180	240	
On-state resistance R <sub>E</sub>					
$V_{\rm IN}$ = 10 V, $I_{\rm D}$ = 3.5 A, $T_{\rm j}$ = 25 °C		-	80	100	
$V_{\text{IN}}$ = 10 V, $I_{\text{D}}$ = 3.5 A, $T_{\text{j}}$ = 150 °C	$V_{\rm IN} = 10 \text{ V}, I_{\rm D} = 3.5 \text{ A}, T_{\rm j} = 150 \text{ °C}$				
Nominal load current (ISO 10483)	I <sub>D(ISO)</sub>	3.5	-	-	Α
$V_{\rm IN}$ = 10 V, $V_{\rm DS}$ = 0.5 V, $T_{\rm C}$ = 85 °C					

<sup>&</sup>lt;sup>1</sup>If the input current is limited by external components, low drain currents can flow and heat the device. Auto restart behaviour can occur.

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#### **Electrical Characteristics**

Parameter	Symbol	Values			Unit
	Symbol		1		Unit
at T <sub>j</sub> =25°C, unless otherwise specified		min.	typ.	max.	
Characteristics					
Initial peak short circuit current limit	I <sub>D(SCp)</sub>	-	25	-	Α
$V_{IN}$ = 10 V, $V_{DS}$ = 12 V					
Current limit 1)	I <sub>D(lim)</sub>	7	10	15	
$V_{\rm IN}$ = 10 V, $V_{\rm DS}$ = 12 V, $t_{\rm m}$ = 350 $\mu$ s,					
$T_{\rm j}$ = -40+150 °C					
Dynamic Characteristics	•			•	•
Turn-on time $V_{\text{IN}}$ to 90% $I_{\text{D}}$ :	t <sub>on</sub>	-	40	70	μs
$R_{\rm L}$ = 4.7 $\Omega$ , $V_{\rm IN}$ = 0 to 10 V, $V_{\rm bb}$ = 12 V					
Turn-off time $V_{\text{IN}}$ to 10% $I_{\text{D}}$ :	$t_{ m off}$	-	70	150	
$R_{\rm L}$ = 4.7 $\Omega$ , $V_{\rm IN}$ = 10 to 0 V, $V_{\rm bb}$ = 12 V					
Slew rate on 70 to 50% V <sub>bb</sub> :	-dV <sub>DS</sub> /dt <sub>on</sub>	-	1	3	V/µs
$R_{\rm L}$ = 4.7 $\Omega$ , $V_{\rm IN}$ = 0 to 10 V, $V_{\rm bb}$ = 12 V					
Slew rate off 50 to 70% V <sub>bb</sub> :	dV <sub>DS</sub> /dt <sub>off</sub>	-	1	3	
$R_{\rm L}$ = 4.7 $\Omega$ , $V_{\rm IN}$ = 10 to 0 V, $V_{\rm bb}$ = 12 V					
Protection Functions <sup>2)</sup>					
Thermal overload trip temperature	$T_{it}$	150	165	-	°C
Unclamped single pulse inductive energy	E <sub>AS</sub>				mJ
$I_{\rm D}$ = 3.5 A, $T_{\rm j}$ = 25 °C, $V_{\rm bb}$ = 32 V		1000			
$I_{\rm D}$ = 3.5 A, $T_{\rm j}$ = 150 °C, $V_{\rm bb}$ = 32 V		225			
Inverse Diode					
Inverse diode forward voltage	V <sub>SD</sub>	-	1	_	V
$I_{\rm F} = 5*3.5 {\rm A}, \ t_{\rm m} = 300 \ \mu {\rm S}, \ V_{\rm IN} = 0 \ {\rm V}$					

<sup>&</sup>lt;sup>1</sup>Device switched on into existing short circuit (see diagram Determination of I  $_{D(lim)}$ ). If the device is in on condition and a short circuit occurs, these values might be exceeded for max. 50  $\mu$ s.

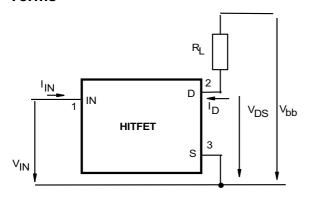
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<sup>&</sup>lt;sup>2</sup>Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation

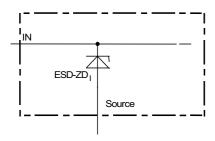


#### **Block Diagramm**

#### **Terms**

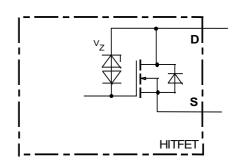


#### Input circuit (ESD protection)

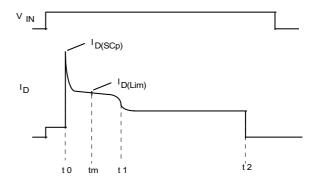


ESD zener diodes are not designed for DC current > 2 mA @  $V_{IN}$ >10V.

#### Inductive and overvoltage output clamp



#### Short circuit behaviour



t<sub>0</sub>: Turn on into a short circuit

t<sub>m</sub>: Measurementpoint for I<sub>D(lim)</sub>

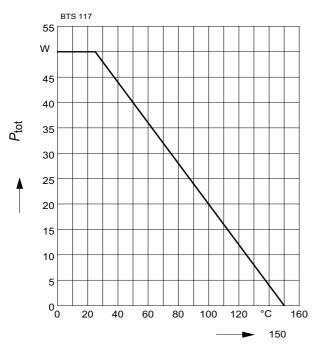
t<sub>1</sub>: Activation of the fast temperature sensor and regulation of the drain current to a level where the junction temperature remains constant.

t2: Thermal shutdown caused by the second temperature sensor, achieved by an integrating measurement.

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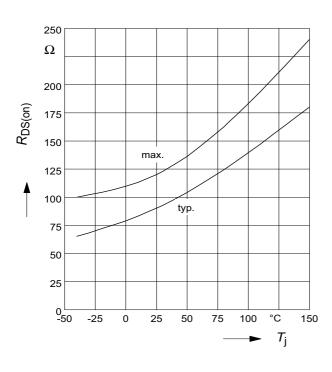


# Maximum allowable power dissipation $P_{tot} = f(T_c)$



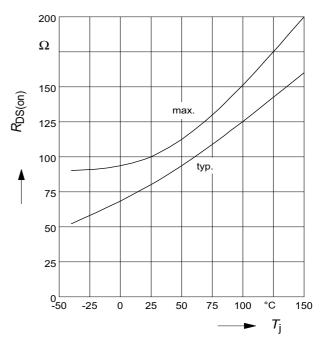
#### On-state resistance

$$R_{ON} = f(T_i); I_D = 3.5A; V_{IN} = 5V$$



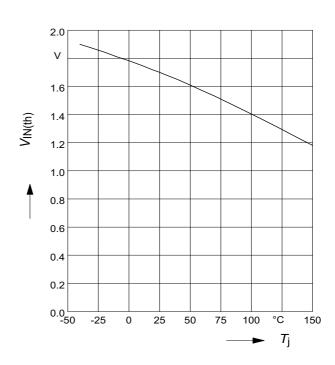
#### On-state resistance

$$R_{ON} = f(T_i); I_D = 3.5A; V_{IN} = 10V$$



#### Typ. input threshold voltage

$$V_{IN(th)} = f(T_j); I_D=0.7mA; V_{DS}=12V$$

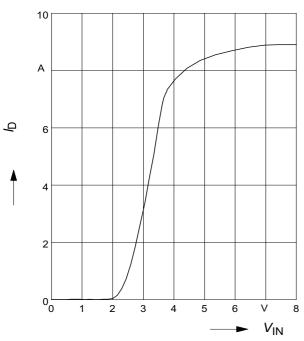


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#### Typ. transfer characteristics

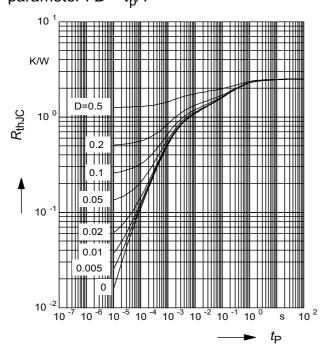
$$I_D = f(V_{IN}); V_{DS} = 12V; T_j = 25^{\circ}C$$



#### **Transient thermal impedance**

$$Z_{\text{thJC}} = f(t_{\text{p}})$$

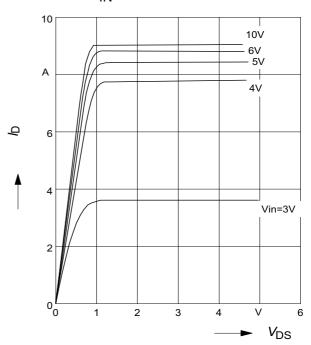
parameter :  $D = t_p/T$ 



#### Typ. output characteristic

 $I_D = f(V_{DS}); T_j = 25$ °C

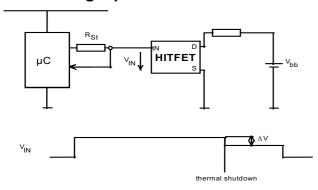
Parameter: V<sub>IN</sub>





#### **Application examples:**

## Status signal of thermal shutdown by monitoring input current



$$\Delta V = R_{\rm ST} \ ^*I_{\rm IN(3)}$$

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**Package Outlines** 

### 1 Package Outlines

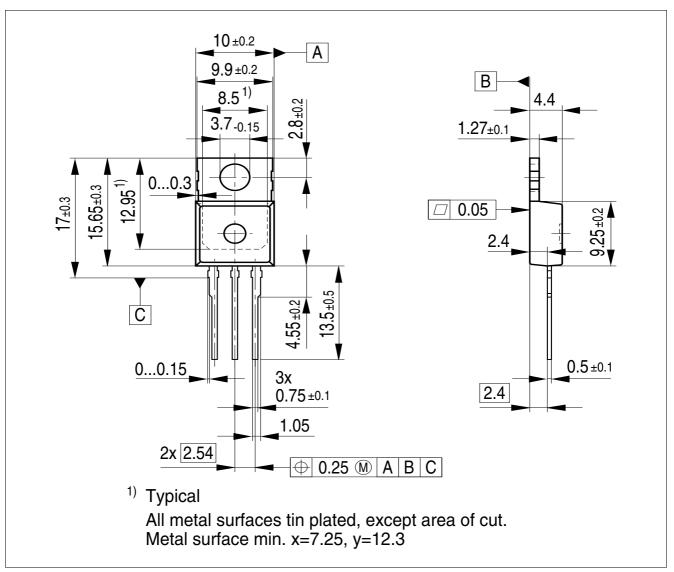


Figure 1 PG-TO220-3-1

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).





**Revision History** 

## 2 Revision History

Version	Date	Changes
Rev. 1.4	2012-07-11	released through hole automotive green Datasheet
		Package drawing update, removed staggered package
		added through hole version in green package
Rev. 1.3	2008-12-10	Package drawing update
Rev. 1.2	2008-08-11	Package information updated, removed through hole version
Rev. 1.1	2008-02-22	Package parameter (humidity and climatic) removed in Maximum ratings AEC icon and RoHS icon added
		Green product and AEC qualified added to feature list
		added Protection footnote on Page 4 and changed front page general description
		Package infromation updated to green
		Green explanation added
Rev. 1.0	2000-05-19	released production version

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